Technical Data Data Sheet 3170, Rev. A

403CMQ080/403CMQ100 SCHOTTKY RECTIFIER

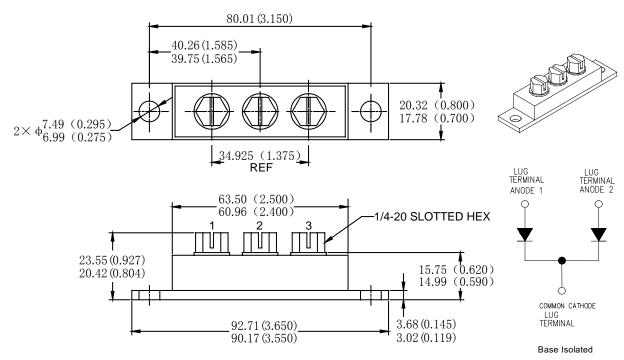
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection Converters UPS System Welding

Features:

- 175 °C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Mechanical Dimensions: In Inches / mm



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2 Suffix R Denotes for Reversed Polarity.

PRM4 (Isolated)



Data Sheet 3170, Rev. A **Maximum Ratings**:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V _{RWM}	-	80(403CMQ080) 100(403CMQ100)		V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C = 85 °C,	200	per leg	Α
Current		rectangular wave form	400	per device	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	3960		А
Non-Repetitive Avalanche Energy (per leg)	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 30 mH	15		mJ
Repetitive Avalanche Current (per leg)	I _{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T _J max. V _A = 1.5 x V _R typical	1		Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 200 A, Pulse, T _J = 25 °C	0.83	V
(per leg) *		@ 400 A, Pulse, T _J = 25 °C	0.97	
	V_{F2}	@ 200 A, Pulse, T _J = 125 °C	0.69	V
		@ 400 A, Pulse, T _J = 125 °C	0.82	
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R, T_J = 25 ^{\circ}\text{C}$	6	mA
	I _{R2}	$@V_R = \text{rated } V_R, T_J = 125 ^{\circ}\text{C}$	140	mA
Max. Junction Capacitance	C _T	$@V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$	5500	pF
(per leg)		f _{SIG} = 1 MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm	5.0	nΗ
(per leg)		from package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

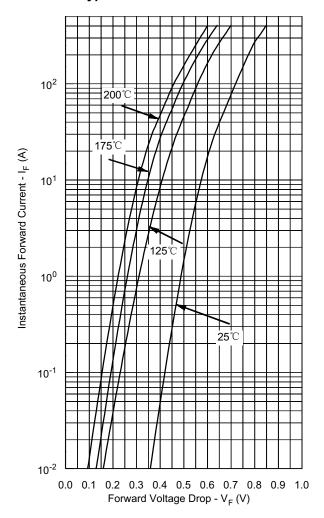
Characteristics	Symbol	Condition	Specification		Units	
Max. Junction Temperature	TJ	-	-55 to +175		°C	
Max. Storage Temperature	T _{stg}	-	-55 to +175		°C	
Maximum Thermal Resistance Junction to Case (per leg)	R _{eJC}	DC operation	0.40		°C/W	
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.20		°C/W	
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.10		°C/W	
Approximate Weight	wt	-	79		g	
Mounting Torque	T _M	-	Mounting Torque Base Terminal Torque	24 (min) 35 (max) 35 (min) 46 (max)	Kg-cm	
Case Style	PRM4 Isolated					

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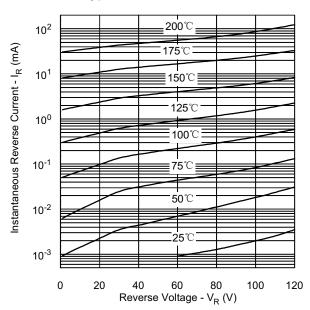
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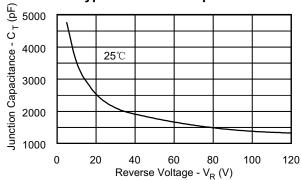
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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